

January 2010

FSEZ2016 — Low-Power Green-Mode EZSWITCH without Secondary Side Feedback Circuitry

Features

- Linearly Decreasing PWM Frequency
- Green Mode Under Light-load and Zero-Load Conditions
- Constant Voltage (CV) and Constant Current (CC) around ±25% without Secondary Side Feedback Circuitry
- Precise Constant Voltage (CV) at ±5% by Secondary Side Feedback Circuitry
- Low Startup Current: 8µA
- Low Operating Current: 3.6mA
- Leading-Edge Blanking (LEB)
- Constant Power Limit
- Universal AC Input Range
- Synchronized Slope Compensation
- 140°C OTP Sensor with Hysteresis
- V_{DD} Over-Voltage Clamping
- Cycle-by-Cycle Current Limiting
- Under-Voltage Lockout (UVLO)
- Fixed PWM Frequency with Hopping
- Gate Output Maximum Voltage Clamped at 17V

Applications

General-purpose switching-mode power supplies and flyback power converters, such as:

- Battery Chargers for Cellular Phones, Cordless Phones, PDAs, Digital Cameras, Power Tools
- Power Adapters for Ink Jet Printers, Video Game Consoles, Portable Audio Players
- Open-Frame SMPS for TV/DVD Standby and Auxiliary Supplies, Home Appliances, Consumer Electronics
- Replacement for Linear Transformers and RCC SMPS
- PC 5V Standby Power

Description

This highly integrated PWM controller provides several features to enhance the performance of low-power flyback converters. To minimize standby power consumption, a proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load and zero-load conditions. This green mode enables the power supply to meet international power conservation requirements. The supply voltage V_{DD} is also used for feedback compensation, to regulate the output voltage without requiring a conventional TL431 and a photo-coupler. A typical output CV/CC characteristic is shown in Figure 1.

Another advantage of the FSEZ2016 is that the typical startup current is only 8μ A, while the typical operating current can be as low as 3.6mA. A large startup resistance can be used to achieve even higher power conversion efficiency.

FSEZ2016 integrates frequency hopping function internally to reduce EMI emissions with minimum line filters. Also, built-in synchronized slope compensation maintains the stability of peak current-mode control. Proprietary internal compensation ensures constant output power limiting over a universal range of AC input voltages, from $90V_{AC}$ to $264V_{AC}$.

The FSEZ2016 provides many protection functions. Pulse-by-pulse current limiting ensures constant output current, even if a short circuit occurs. The internal protection circuit disables PWM output if V_{DD} exceeds 22.7V. The gate output is clamped at 17V to protect the power MOS from over-voltage damage. The built-in over-temperature protection (OTP) function shuts down the controller at 140°C with a 30°C hysteresis.

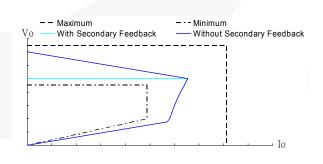
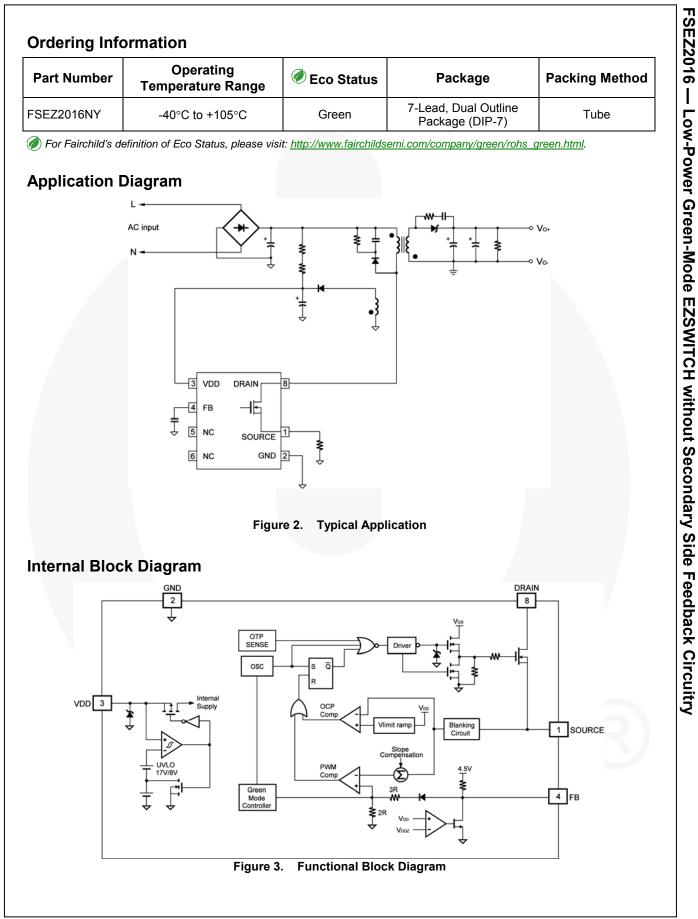
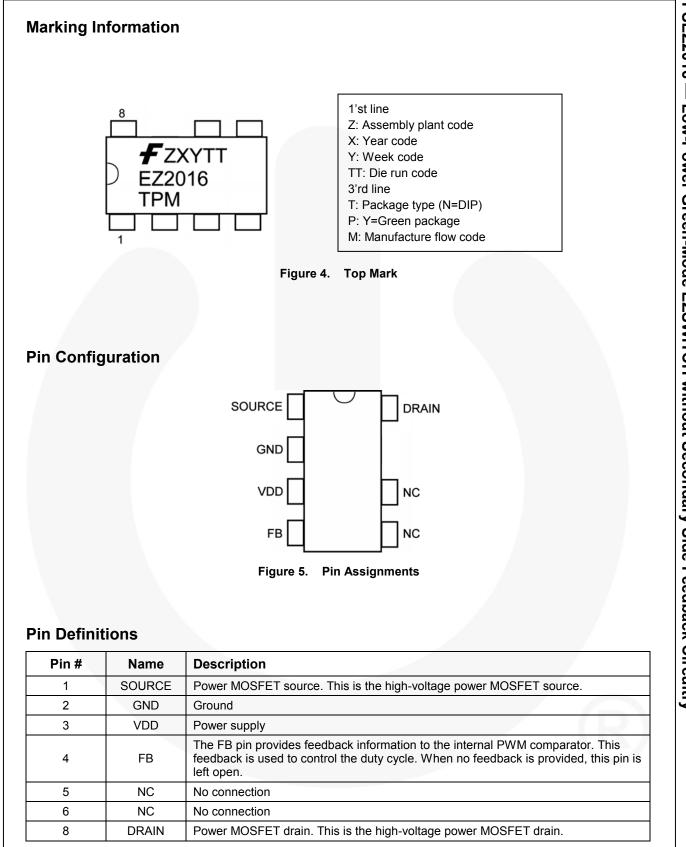


Figure 1. Typical Output V-I Characteristic





Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

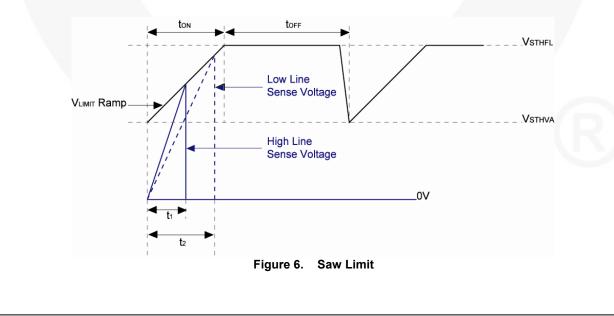
Symbol	Parameter			Max.	Unit
V _{DD}	DC Supply Voltage ^(1, 2)			30	V
V _{FB}	Input Voltage to FB Pin	1	-0.3	7.0	V
V _{SENSE}	Input Voltage to Sense	Pin	-0.3	7.0	V
PD	Power Dissipation (T _A =25°C)			1.2	W
heta ja	Thermal Resistance (Junction to Air)			98.7	°C/W
TJ	Operating Junction Temperature			150	°C
T _{STG}	Storage Temperature Range			150	°C
TL	Lead Temperature (Wave Soldering or IR, 10 Seconds)			260	°C
ESD Electrostatic Discharge Capability	Electrostatic	Human Body Model (JEDEC:JESD22_A114)		2	KV
	Charged Device Model (JEDEC:JESD22_C101)		1	KV	

Notes:

1. All voltage values, except differential voltages, are given with respect to GND pin.

2. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

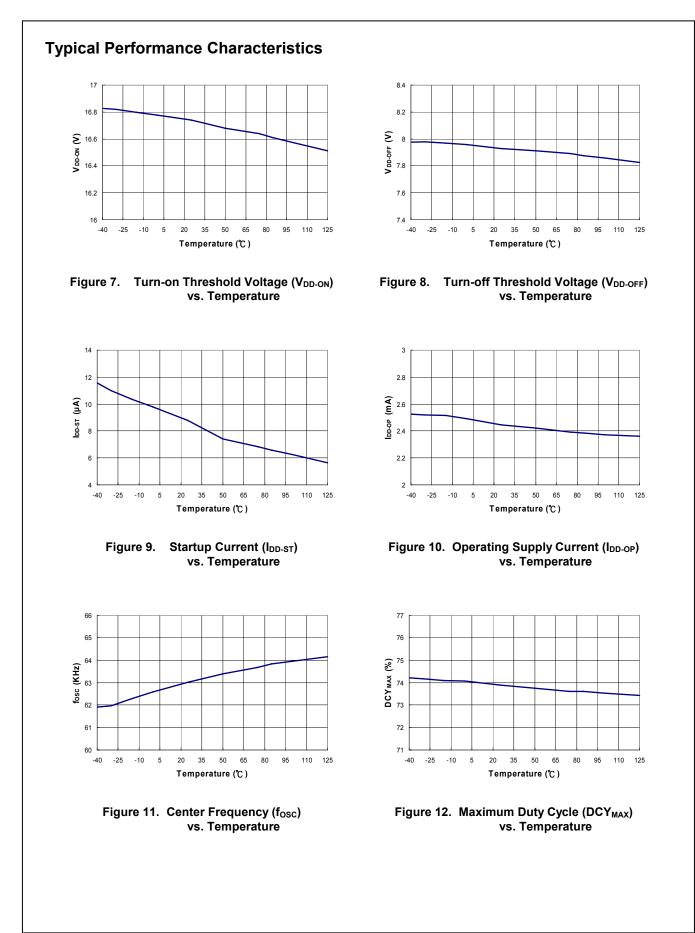
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{DD} Sectio	bn					<u> </u>
N/		With Secondary Feedback			20.0	- V
V _{DD-OP}	Continuously Operation Voltage	Without Secondary Feedback			22.7	
$V_{\text{DD-ON}}$	Turn-on Threshold Voltage		16	17	18	V
$V_{\text{DD-OFF}}$	Turn-off Threshold Voltage		7.5	8.0	8.5	V
I _{DD-ST}	Startup Current	$V_{DD}=V_{DD-ON}-0.1V$		8	20	μA
I _{DD-OP}	Operating Supply Current	C _L =1nF		3.6	4.6	mA
$V_{\text{DD-G-OFF}}$	V _{DD} Low-threshold Voltage to Exit Green-off Mode			V _{DD-OFF} +1.3		V
Feedback	Input Section					
A _V	Input-Voltage to Current-Sense Attenuation			0.35		V/V
Z _{FB}	Input Impedance	I _{FB} =0.1mA to 0.2mA		4.6		kΩ
V _{FB-OPEN}	Open-Loop Voltage		4.5			V
N		FB is Open	20.7	22.7	24.7	V
V _{DD-FB} V _{DD} Feedback Threshold Voltage		I _{FB} =0.4mA	18.4	20.4	22.4	V
Current-S	ense Section					
t _{PD}	Propagation Delay			100	150	ns
		V _{DD} =18V		0.83		V
V_{STHVA}	Current Limit Valley Threshold Voltage	V _{DD} =15V		0.74		V
		V _{DD} =10V		0.59		V
VSTHFL		V _{DD} =18V		1.15		V
	Current Limit Flat Threshold Voltage	V _{DD} =15V		1.04		V
		V _{DD} =10V		0.84		V
t _{LEB}	Leading-Edge Blanking Time		220	310	400	ns

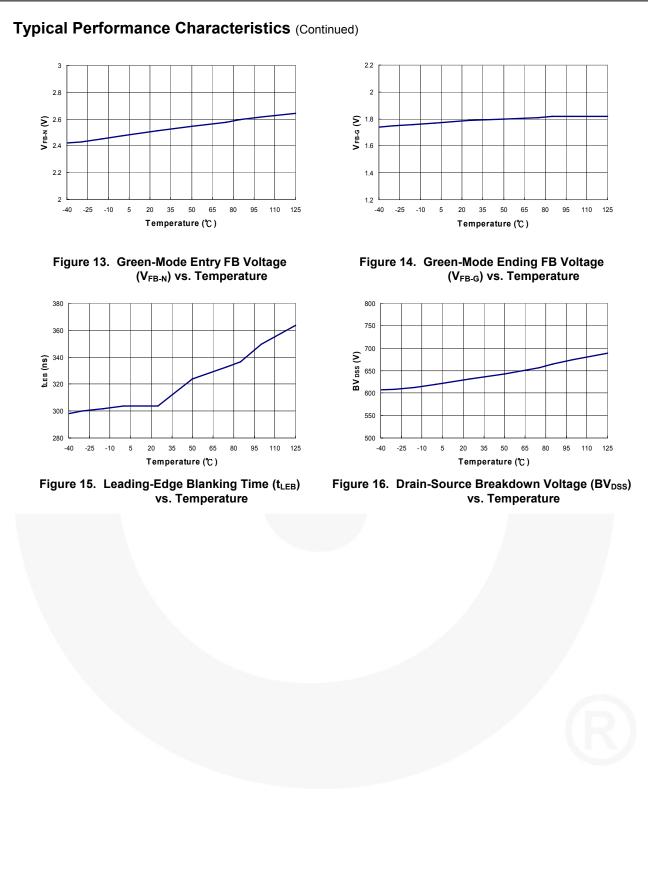


Electrical Characteristics (Continued)

Unless otherwise noted, V_{DD} =15V and T_A=25°C.

Symbol		Parameter	Conditions	Min.	Тур.	Max.	Units
Oscillator S	Section						
fosc	_	Center Frequency		60	65	70	
	Frequency	Hopping Range		±4.1	±4.7	±5.3	- kHz
t _{HOP}	Hopping Perio	bd			4		ms
f _{OSC-G}	Green Mode I	Frequency		14.5	17.0	19.5	KHz
V_{FB-N}	Green Mode I	Entry FB Voltage		2.3	2.6	2.9	V
V_{FB-G}	Green Mode I	Ending FB Voltage			V _{FB-N} - 0.75		V
V_{FB-Z}	Zero Duty Cy	cle FB Voltage			1.4		V
S _G	Green Mode I	Modulation Slope		40	70	100	Hz/m∖
f _{DV}	Frequency Va	ariation vs. V _{DD} Deviation	V _{DD} =10 to 22V			5	%
f _{DT}	Frequency Va Deviation	ariation vs. Temperature	T _A = -20 to 85°C		1.5	5.0	%
Internal MC	SFET Section	on					
DCY _{MAX}	Maximum Dut	ty Cycle		69	74	79	%
BV _{DSS}	Drain-Source	Breakdown Voltage	I _D =250µA, V _{GS} =0V	600			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown V Coefficient	oltage Temperature	I _D =250µA, Referenced to 25°C		0.6		V/°C
ls	Maximum Cor Diode Forwar	ntinuous Drain-Source d Current				1	A
I _{SM}	Maximum Pul Forward Curre	sed Drain-Source Diode ent				4	А
R _{DS(ON)}	Static Drain-S	Source On-Resistance	I _D =0.5A, V _{GS} =10V		9.3	11.5	Ω
	Drain-Source Leakage Current		V_{DS} =600V, V_{GS} =0V, T_C =25°C			5	μA
I _{DSS}			V _{DS} =480V, V _{GS} =0V, T _C =100°C			10	μA
t _{D-ON}	Turn-on Delay	y Time	V_{DS} =300V, I _D =1.1A, R _G =25 Ω		7	24	ns
tr	Rise Time				21	52	ns
t _{D-OFF}	Turn-off Delay	y Time			13	36	ns
t _f	Fall Time				27	64	ns
CISS	Input Capacit	ance	V_{GS} =0V, V_{DS} =25V, f_{S} =1MHz		130	170	pF
C _{OSS}	Output Capac	citance			19	25	pF
Over Temp	erature Prote	ection (OTP)					
T _{OTP}	Protection Ju	nction Temperature			140		°C
T _{OTP-RESTART}	Restart Junct	ion Temperature			110		°C





FSEZ2016 — Low-Power Green-Mode EZSWITCH without Secondary Side Feedback Circuitry

Operation Description

FSEZ2016 devices integrate functions for low-power switch-mode power supplies. The following descriptions highlight the key features of the FSEZ2016.

Startup Current

The required startup current is only 8µA. This allows a high-resistance, low-wattage startup resistor to supply the controller's startup power. A 1.5M Ω /0.25W startup resistor can be used over a wide input range (100V-240V_{AC}) with very little power loss.

Operating Current

The operating current is normally 3.6mA, which results in higher efficiency and reduces the required V_{DD} hold-up capacitance. A 10μ F/25V V_{DD} hold-up capacitor can be used over a wide input range (90V-264V_{AC}) with very little power loss.

Green-Mode Operation

The proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load and zero-load conditions. The on-time is limited to provide better protection against brownouts and other abnormal conditions. Power supplies using the FSEZ2016 can meet international restrictions regarding standby power-consumption.

Constant Voltage (CV) and Constant Current (CC) without Feedback

The FSEZ2016 can tightly regulate the output voltage and provide over-current protection without requiring secondary-side feedback signals. For improved CV and CC accuracy, the transformer leakage inductance should be reduced as much as possible.

Over-Temperature Protection (OTP)

The FSEZ2016 has a built-in temperature-sensing circuit to shut down PWM output if the junction temperature exceeds 140°C. While PWM output is shut down, the V_{DD} voltage gradually drops to the UVLO voltage. Some of the internal circuits are shut down, and V_{DD} gradually starts increasing again. When V_{DD} reaches 17V, all the internal circuits, including the temperature-sensing circuit, operate normally. If the junction temperature is still higher than 140°C, the PWM controller shuts down immediately. This situation continues until the temperature drops below 110°C. The PWM output is then turned back on. The temperature hysteresis window for the OTP circuit is 30°C.

V_{DD} Over-Voltage Clamping

 V_{DD} over-voltage clamping is built in to prevent damage from over-voltage conditions. When V_{DD} exceeds 22.7V, PWM output is shut down. Over-voltage conditions may be caused by an open photo-coupler loop or a short circuit in the output.

Oscillator Operation

The oscillation frequency is fixed at 65KHz.

Leading-Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs at the sense-resistor. To avoid premature termination of the switching pulse, a 310ns leadingedge blanking time is built in. Conventional RC filtering is not necessary. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate drive.

Constant Output Power Limit

When the SENSE voltage across the sense resistor Rs reaches the threshold voltage, the output GATE drive is turned off following a small propagation delay, tpp. This propagation delay introduces an additional current proportional to t_{PD}•V_{IN}/L_P. The propagation delay is nearly constant, regardless of the input line voltage VIN. Higher input line voltages result in larger additional currents. Under high input-line voltages, the output power limit is higher than under low input-line voltages. Over a wide range of AC input voltages, the variation can be significant. To compensate for this, the threshold voltage is adjusted by adding a positive ramp (Vlimit ramp). This ramp signal can vary from 0.74V to 1.04V and flattens out at 1.04V. A smaller threshold voltage forces the output GATE drive to terminate earlier, reducing total PWM turn-on time and making the output power equal to that of the low line input. This proprietary internal compensation feature ensures a constant output power limit over a wide range of AC input voltages (90V-264V_{AC}).

Under Voltage Lockout (UVLO)

The turn-on/turn-off thresholds are fixed internally at 17V and 8V. To enable the FSEZ2016 during startup, the hold-up capacitor must first be charged to 17V through the startup resistor. The hold-up capacitor continues to supply V_{DD} before energy can be delivered from the auxiliary winding of the main transformer. V_{DD} must not drop below 8V during this startup process. This UVLO hysteresis window ensures that the hold-up capacitor capacitor can adequately supply V_{DD} during startup.

Gate Output

The BiCMOS output stage is a fast totem-pole gate driver. Cross-conduction is avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 17V Zener diode to protect the power MOSFET transistors against any harmful over-voltage gate signals.

Operation Description (Continued)

Slope Compensation

The sensed voltage across the current sense resistor is used for current mode control and pulse-by-pulse current limiting. The built-in slope compensation improves power supply stability. Furthermore, it prevents sub-harmonic oscillations that normally would occur because of peak current mode control. A positively sloped, synchronized ramp is activated with every switching cycle. The slope of the ramp is:

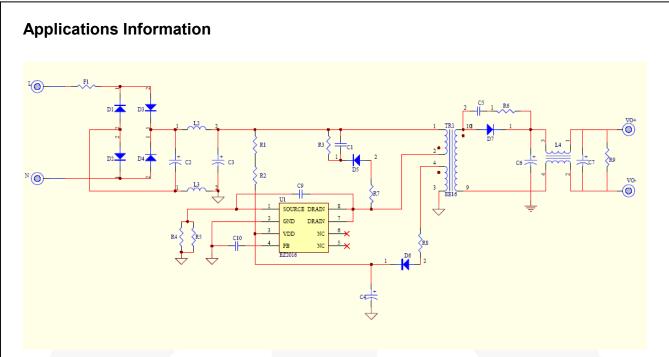
$0.33 \times Duty$

Duty(max.)

Noise Immunity

(1)

Noise from the current sense or the control signal may cause significant pulse-width jitter, particularly in continuous-conduction mode. Slope compensation helps alleviate this problem. Good placement and layout practices should be followed. The designer should avoid long PCB traces and component leads. Compensation and filter components should be located near the FSEZ2016. Finally, increasing the power-MOS gate resistance is advised.





BOM

Reference	Component	Reference	Component
C1	CC 4.7nF/1kV	F1	R 1Ω/1W
C2	EC 4.7µF/400V 105°C	L2	Inductor 4.7µH
C3	EC 4.7µF/400V 105°C	L3	Inductor 470µH
C4	EC 10µF/50V 105°C	L4	Inductor 80µH
C5	CC 1nF/1kV	R1	R 750kΩ
C6	EC 560µF/10V	R2	R 750kΩ
C7	EC 560µF/10V	R3	R 100kΩ
C9	Open	R4	R 10Ω
C10	CC 1nF	R5	R 2.2Ω
D1	Diode 1N4007	R6	R 47Ω
D2	Diode 1N4007	R7	R 270Ω
D3	Diode 1N4007	R8	R 0Ω
D4	Diode 1N4007	R9	R 2kΩ
D5	Diode FR107	T1	Transformer EE-16
D6	Diode FR102	U1	IC FSEZ2016
D7	Diode SB560		

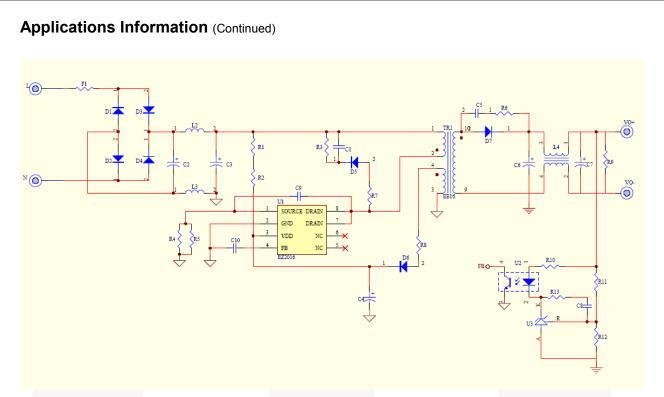
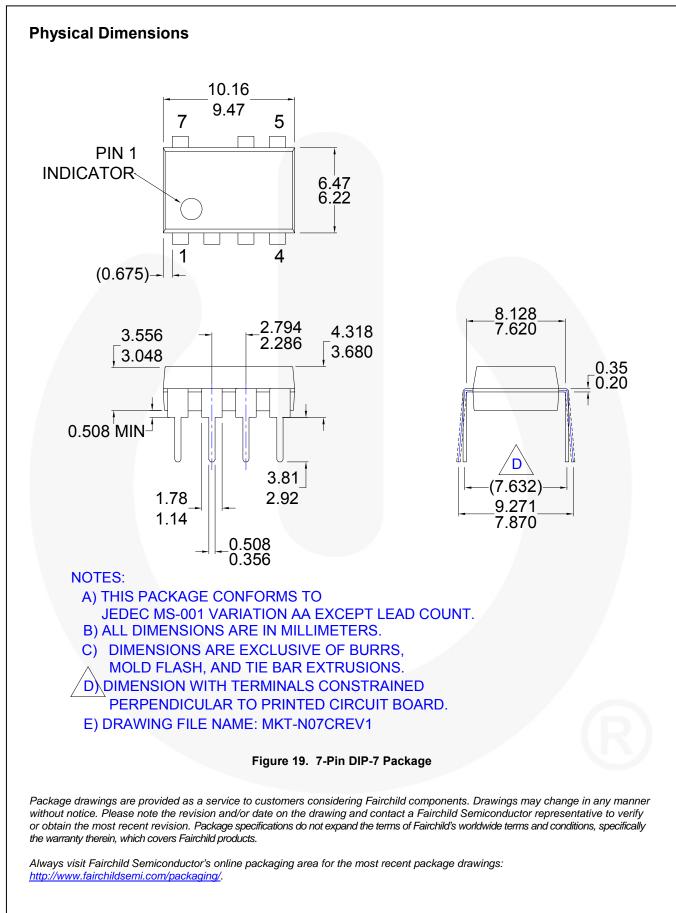


Figure 18. Reference Circuit (with Secondary-Side Feedback)

BOM

Reference	Component	Reference	Component	
C1	CC 4.7nF/1kV	L3	Inductor 470µH	
C2	EC 4.7µF/400V 105°C	L4	Inductor 80µH	
C3	EC 4.7µF/400V 105°C	R1	R 750kΩ	
C4	EC 10µF/50V 105°C	R2	R 750kΩ	
C5	CC 1nF/1kV	R3	R 100kΩ	
C6	EC 560µF/10V	R4	R 10Ω	
C7	EC 560µF/10V	R5	R 2.2Ω	
C8	CC 2.2nF	R6	R 47Ω	
C9	Open	R7	R 270Ω	
C10	CC 1nF	R8	R 0Ω	
D1	Diode 1N4007	R9	R 2kΩ	
D2	Diode 1N4007	R10	R 560Ω	
D3	Diode 1N4007	R11	R 20kΩ	
D4	Diode 1N4007	R12	R 20kΩ	
D5	Diode FR107	R13	R 20kΩ	
D6	Diode FR102	T1	Transformer EE-16	
D7	Diode SB560	U1	IC FSEZ2016	
F1	R 1Ω/1W	U2	IC PC817	
L2	Inductor 4.7µH	U3	IC TL431	

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